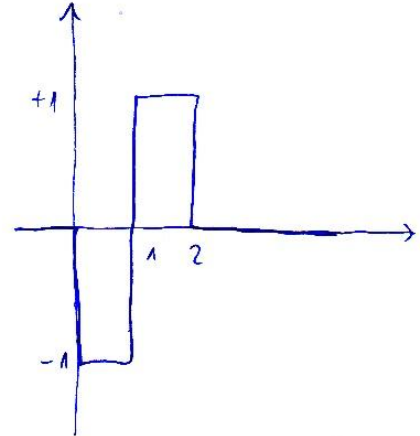
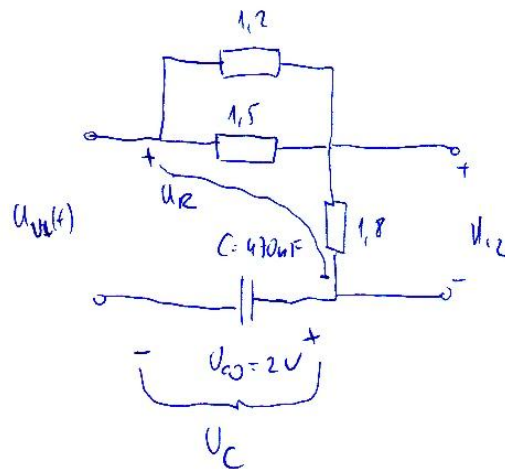


ELE-A

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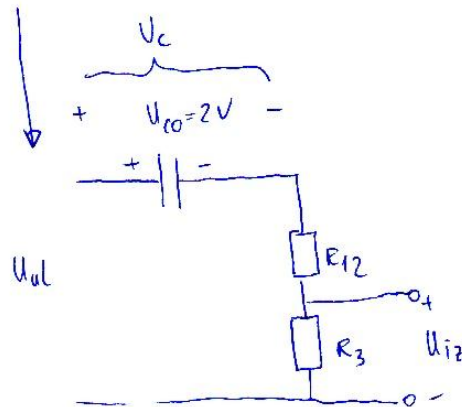
ZA SKLOP NA SLICI a) PRIZNATELJEK JE ULAZNI NAPON
 $U_{ul}(t)$

$t=0 \quad U_{C0} = 2V$



$U_{ul} = U_R + U_C = U_C + U_R$

$R_{12} = R_1 || R_2 = 0,667 k\Omega$



→ skicirajka
i kad im
učinak od
GE

a) ODREDI VREMENSKU KONSTANTU

$\tau = C \cdot (R_{12} + R_3) = 470 \cdot 10^{-6} \cdot (667 + 1800) = \underline{\underline{1,16 ms}}$

b) NAPISI IZRAZ ZA IZLAZNI NAPON, TE IZ R

$0 < t < 1 ms$

$1 < t < 2 ms$

$2 < t$

te izračunaj U_{i2} $t=0, t=1, t=2, t=3 ms$

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$$U_c(t) = U_{co} + (U_{uc} - U_{co}) \left[1 - \exp \frac{-(t-t_i)}{\tau} \right] \rightarrow \text{RASHČA EKSPONENCIJALNA}$$

↑
KONVOZI

$$U_R(t) = U_{uc} - U_c = U_{uc} - U_{co} \left[\exp \frac{-(t-t_i)}{\tau} \right]$$

$$U_{12} = k \cdot U_{UR} = \frac{R_3}{R_{12} + R_3} \cdot U_{uc} = k (U_{uc} - U_c)$$

$$k = \frac{R_3}{R_{12} + R_3} = \underline{\underline{0,73}}$$

$$t = 0$$

$$U_{uc} = 0 \quad U_{co} = U_c = 2V$$

PRIJE SKOKA

$$t = 0^-$$

$$U_{12}(0^-) = k(U_{uc} - U_{co}) = 0,73 \cdot (0 - 2) = \underline{\underline{-1,46V}}$$

NAKON SKOKA

$$t = 0^+$$

 ΔU_{uc}

$$U_{12}(0^+) = U_{12}^- + k \Delta U_{uc} = -1,46 + 0,73 \cdot (-1) = \underline{\underline{-2,19V}}$$

$$\underline{\underline{0 < 1 < 1}}$$

$$U_{12}(t) = U_{120^+} \cdot \exp \frac{-(t-0)}{\tau} =$$

PRIJE SKOKA (1)

$$t = 1^-$$

$$U_{12}(1^-) = U_{120^+} \cdot \exp \frac{-(1-0)}{\tau} = -2,19 \cdot \exp \frac{-1}{1,16} = \underline{\underline{-0,925V}}$$

ELE 14/11/11 ③

Poslije skoka (1)

$$t = 1^+$$

$$\Delta U_{ul} = -1 \rightarrow 1 = +2V$$

$$U_{121^+} = U_{121^-} + K \Delta U_{ul} = -0,925 + 0,73 \cdot 2 = \underline{\underline{0,535V}}$$

 $1 < t < 2$

$$U_{12}(t) = U_{121^+} \cdot \exp\left(\frac{-t-t_1}{\tau}\right) =$$

 $t = 2^-$ prije skoka

$$U_{122^-} = U_{121^+} \cdot \exp\left(\frac{-t_2-t_1}{\tau}\right) = 0,535 \cdot \exp\frac{-2-1}{1,16} = \underline{\underline{0,226V}}$$

 $t = 2^+$ poslije skoka

$$\Delta U_{ul} = 1 \rightarrow 0 = \underline{\underline{-1}}$$

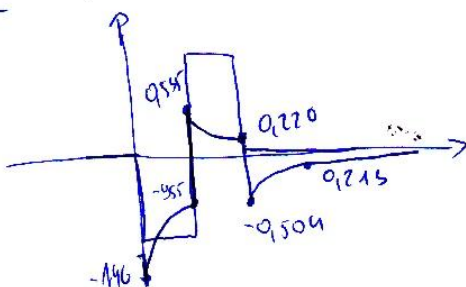
$$U_{122^+} = U_{122^-} + K \cdot \Delta U_{ul} = 0,226V + 0,73 \cdot (-1) = \underline{\underline{-0,504V}}$$

 $t > 2$

$$U_{12}(t) = U_{122^+} \cdot \exp\left(\frac{-t-t_2}{\tau}\right)$$

$$t = t_3 = 3ms$$

$$U_{123} = U_{122^+} \cdot \exp\left(\frac{t_3-t_2}{\tau}\right) = -0,504 \cdot \exp\frac{-(3-2)}{1,16} = \underline{\underline{0,213V}}$$

Skica

ELE 4 14/11/11

2. SVOJSTVA POKU VODIČASilicij P TIPA HOMOGENO JE DOPIRAN 10^{16} cm^{-3}

p-tip akceptor

DODA LI SE U SI DRUGA PRIMJESA FERMIVELA ENERGIJA ĆE SE POMAKNUTI
ZA $0,15 \text{ eV}$, A SPECIFIČNA VODLJIVOST ĆE SE SMANJITIPOKRETLJIVOST SLOBODNIH
(e) $820 \text{ cm}^2/\text{Vs}$ $400 \text{ cm}^2/\text{Vs}$ (šupljine) $T = 300 \text{ K}$

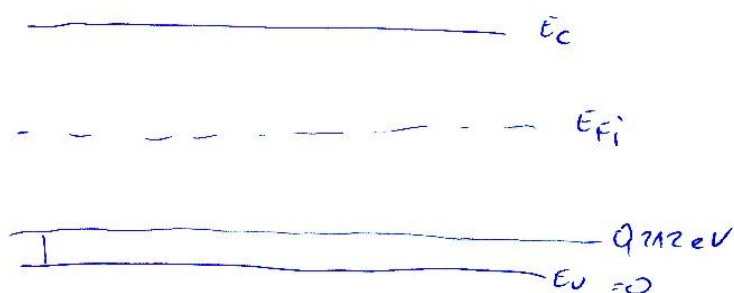
a) TIP IZADJE DRUGE PRIMJESJE

Šupljini $N_A = 10^{16} \text{ cm}^{-3}$, $n_i(300) = 1,45 \cdot 10^{10} \text{ cm}^{-3}$

$$\Rightarrow N_A \gg n_i \quad p_1 = N_A = 10^{16} \text{ cm}^{-3}$$

$$p_1 = n_i \cdot \exp \left(\frac{E_{Fi} - E_F}{\frac{E_T}{kT}} \right) \rightarrow \text{RAČUNATI} \quad E_{Fi} - \text{položaj u intrinzično}$$

$$E_F = E_{Fi} - kT \cdot \ln \frac{p_1}{n_i} = 0,56 \text{ eV} - \frac{300}{11600} \cdot \ln \left(\frac{10^{16}}{1,45 \cdot 10^{10}} \right) = \underline{\underline{0,212 \text{ eV}}}$$

P-TIP E_F ISPOD SREDINE ZA BRANJEKOB POJASA ✓

a) TIP i IIAC DROGE PRIMJES

$$\Delta E_F = 0,15 \text{ eV}$$

→ SPEC. VODLJIVOST SE SMANJUJE $\sigma \downarrow$

GDJE KOD ZAKRŠI E_{Fi} NEĆE SE PROMJENI VODLJIVOST JER I DA ΔE_{Fi}



$$\sigma_i = q \mu_p P_1$$

→ AKO $\sigma \downarrow$ $P_1 > P_2$

$$P_2 \ll q \mu_p P_2$$

→ pomiće se prema gore

→ postaje slabiji P-TIP

E_F SE UDALJUJE OD VALENTNOG POJASA

→ DRUGI TIP PRIMJES JE DOKUPI JER DOBIJAM SLABIJI P-TIP

$$P_2 = n_i \exp \frac{E_{Fi} - E_{F2}}{E_F}$$

$$E_{F2} = E_{F1} + 0,15 \text{ eV} = E_{F1} + \Delta E_F = 0,711 + 0,15 = \underline{0,862 \text{ eV}}$$

$$= 1,45 \cdot 10^{10} \exp \frac{0,56 - 0,862}{\frac{300}{11600}} = 3,06 \cdot 10^{13} \quad P_2 \gg n_i \quad \curvearrowright$$

$$P_2 \sim N_A - N_D = N_{\text{netto}} = N_D = N_A - P = 10^{16} - P_2 = 10^{16} - 3,06 \cdot 10^{13} = \underline{9,97 \cdot 10^{15} \text{ cm}^{-3}}$$

→ KADA DODAJEM DOKUP E $E_F \uparrow$, KADA DODAJEM AKCEPTOR E $E_F \downarrow$

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b) KONCENTRACIJA NOSIOCA KAKO 2. DOPIRAN (MANJKIH NOSIOCI

manjši

$$n_2 = n_1^2 / p_2 = \frac{(145 \cdot 10^{10})^2}{306 \cdot 10^{13}} = 6,87 \cdot 10^6 \text{ cm}^{-3}$$

c) SPECIFIČNI OTPOR SI KAO 1. I 2. DOPIRAN

$$g_1 = \frac{1}{r_1} \approx \frac{1}{q \cdot \mu_p \cdot p_1} = \frac{1}{1,6 \cdot 10^{-19} \cdot 400 \cdot 10^{16}} = 1,56 \text{ S/cm}$$

$$g_2 = \frac{1}{r_2} = \frac{1}{q \cdot \mu_p \cdot p_2} = \frac{1}{1,6 \cdot 400 \cdot} = 511 \text{ S/cm}$$

(11) 11/11/11

③ DIODA

S pn dioda ima homogeno dopirane strane

koncentracije PRN $N_D = 2 \cdot 10^{17} \text{ cm}^{-3}$ $N_A = 8 \cdot 10^{15} \text{ cm}^{-3}$ Efektiv širina $W_n = 1 \text{ mm}$ $W_p = 200 \text{ } \mu\text{m}$ površina pn $S = 0,1 \text{ mm}^2 = 0,1 \cdot 10^{-2} \text{ cm}^2$ POKRETLJIVOSTI manjši koef $M_n = 1000 \text{ cm}^2/\text{Vs}$ $M_p = 200 \text{ cm}^2/\text{Vs}$ A VREMENA ŽIVOTA $\tau_n = 0,1 \text{ } \mu\text{s}$ $\tau_p = 0,5 \text{ } \mu\text{s}$ $T = 300 \text{ K}$ a) ODREDI IZKOS STRUJE KROZ DIODU AKO SE NA NJU SPOJI
KROZ PROPUŠNI POLARIZACIJE $U_D = 0,55 \text{ V}$

Dioda je uska, a široka Ali to moramo izreči.

PROMAPIRAMO MANJŠKE KOEFICIENTEp-strana \rightarrow manjši su elektroni. (DIFUZIJSKA DULJINA)

$$L_n = \sqrt{D_n \tau_n} = \sqrt{M_n V_T \tau_n} = \sqrt{1000 \cdot \frac{300}{11600} \cdot 0,1 \cdot 10^{-6}} = 16,08 \cdot 10^{-4} \text{ cm}$$

$$= 16,08 \text{ } \mu\text{m} \quad W_p (200 \text{ } \mu\text{m}) \quad L_n \ll W_p \text{ široka P-strana}$$

(FOR MOGU $N_D \tau_n / L_n$)n-strana \rightarrow manjši su supljine

$$L_p = \sqrt{D_p \tau_p} = \sqrt{M_p V_T \tau_p} = \sqrt{200 \cdot \frac{300}{11600} \cdot 0,5 \cdot 10^{-6}} = 16,08 \text{ } \mu\text{m}$$

$$W_n (1 \text{ mm}) \quad W_n \ll L_p \quad \text{Uska N-strana}$$

Izračun P_{ON}/W_n FORM

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$$I_s = I_{sn} + I_{sp}$$

$$= q \cdot S \left[\underset{\text{elektr}}{D_n \frac{n_{0n}}{L_p}} + \underset{\text{supljiv}}{D_p \frac{p_{0n}}{W_n}} \right] =$$

$$D_n = \mu_n U_T \quad D_p = \mu_p U_T$$

$$N_{0p} = n_i^2 / p_{0p} = \frac{n_i^2}{N_A}$$

$$p_{0n} = \frac{n_i^2}{N_{0n}} = \frac{n_i^2}{N_D}$$

$$= q \cdot S U_T \cdot n_i^2 \left[\frac{\mu_n}{N_A \cdot L_p} + \frac{\mu_p}{N_D \cdot W_n} \right] \quad \left(\frac{\text{svet protok u cm}}{\text{cm}} \right)$$

$$= 1,6 \cdot 10^{-19} \cdot 0,1 \cdot 10^{-2} \frac{300}{11600} (1,45 \cdot 10^{10})^2 \left[\frac{1000}{8 \cdot 10^{15} \cdot 16,08 \cdot 10^{-4}} + \frac{200}{2 \cdot 10^{17} \cdot 1 \cdot 10^{-4}} \right]$$

$$= \dots = \underline{\underline{7,63 \cdot 10^{-14} \text{ A}}}$$

$$I_D = I_s \cdot \left(\exp\left(\frac{U_D}{U_T}\right) - 1 \right) = \dots = \underline{\underline{0,131 \text{ mA}}}$$

b) NACRTAJ RASPODJELU MNJISHI MOSIĆ, IZRAČI I OZNAČI RUBNE TE RAUOTICE KONCENTRACIJE ZA ZADANE PRIKLJUČNE KARAKTERISTIKE

$$p_{0n} = \frac{n_i^2}{n_{0n}} = \frac{n_i^2}{N_D} = \frac{1,45 \cdot 10^{10}}{2 \cdot 10^{17}} = 1,05 \cdot 10^3 \text{ cm}^{-3} \quad \left. \begin{array}{l} \text{RAUOTICE KONCENTRACIJE} \\ \text{IZ TAKOV TO RAU} \end{array} \right\}$$

$$n_{0p} = \frac{n_i^2}{p_{0p}} = \frac{n_i^2}{N_A} = \dots = 2,63 \cdot 10^4 \text{ cm}^{-3}$$

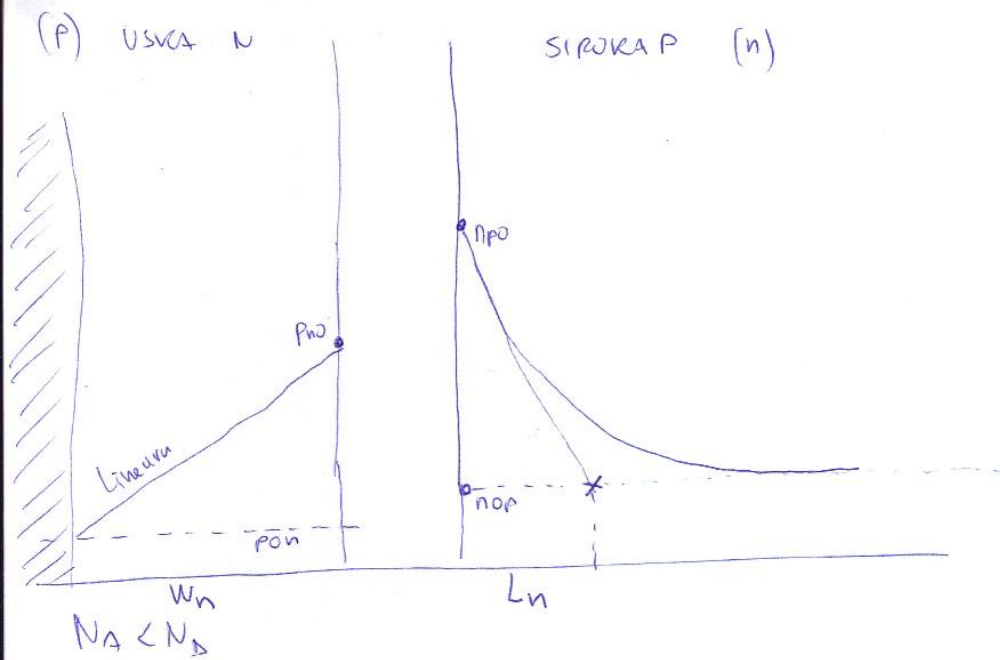
RUBNE KONCENTRACIJE - BOLTZMAN

$$p_{p0} = p_{0n} \exp \frac{U_D}{U_T} = 1,05 \cdot 10^3 \cdot \exp \frac{0,55}{\frac{300}{11600}} = 1,81 \cdot 10^{12} \text{ cm}^{-3}$$

$$n_{p0} = n_{0p} \exp \frac{U_D}{U_T} = 2,63 \cdot 10^4 \cdot \exp \frac{0,55}{\frac{300}{11600}} = 4,53 \cdot 10^{13} \text{ cm}^{-3}$$

- USVA N, SIPOVA P STRANA

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USKA \rightarrow LINEAR

ŠIROKA \rightarrow EXPONENCIJ

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(4)

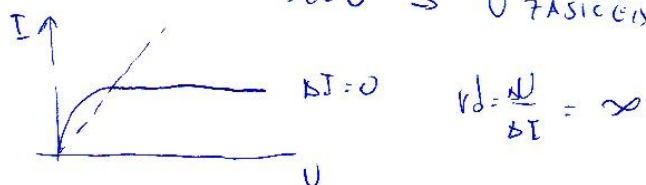
IDEALNI N-KANALNI MOSFET (Si) S PARNI MODULACIJSKI KOEFICIJENT KANALA
 $\rightarrow \lambda = 0$ IMA U POKLOJ TOČKI A IZLAZNI DINAMIČKI ODPOR

$$r_{DA} = 333 \Omega \quad \text{I FAKTOR NAPONA } \mu_A = 2$$

$$\text{STRUJNI KOEF } K = 3 \text{ mA/V}^2$$

a) U KOJEM PODRUČJU RADA SE KANALI A

\rightarrow IDEALNI MOSFET $\lambda = 0 \rightarrow$ U ZASIČENOM $r_D = \infty \quad \mu = \infty$



\Rightarrow TOČKA A = $r_{DA} = 333 \Omega \quad \mu_A = 2 \quad r_D \ll \infty \quad \mu_A \ll \infty \rightarrow$ NIJE U ZASIČENOM

\rightarrow U TRIODNOJ PODRUČJU

b) ODREĐI KAPU PRI V_{GS0} I V_{GS1} I V_{DS1} U TOČKI A

AKO JE U TOČKI B, UŽ V_{GSB} KOJI JE ZA 50% > V_{GS1} I

NEPROMJEŃI NAPON $V_{DSB} = V_{DSA}$, STRUJA MOSFETA $I_{DB} = 24 \text{ mA}$

$$\Rightarrow V_{GSB} = 1.5 V_{GS1} \quad V_{DSB} = V_{DSA}$$

A \rightarrow TRIODNOJ PODRUČJU

$$I_D = K \cdot \left[(V_{GS} - V_{GS0}) V_{DS} - \frac{V_{DS}^2}{2} \right]$$

$$g_m = \left. \frac{\partial I_D}{\partial V_{GS}} \right|_A = \dots = K \cdot V_{DS1}$$

$$r_{DA} = 333 \quad \mu_A = 2$$

$$\mu_A = g_m \cdot r_{DA}$$

$$g_m = \frac{\mu_A}{r_{DA}} = 6 \text{ mA/V} \quad \text{STRUJNA}$$

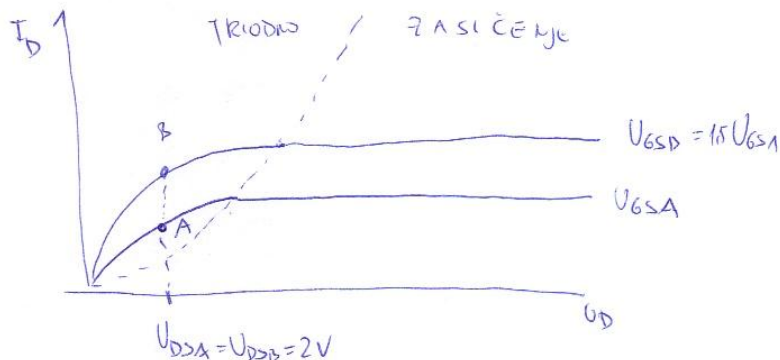
ELE 11 14(11/11)

$$V_{D5A} = g_{mA} / K = \frac{6 \text{ mA/V}}{3 \text{ mA/V}^2} = \underline{\underline{2 \text{ V}}}$$

$$g_d = \frac{1}{r_d} \left. \frac{\partial I_D}{\partial V_{DS}} \right|_A = K \cdot [(V_{GS A} - V_{GS0}) \cdot 1 + V_{D5A}]$$

$$\dots \Rightarrow V_{GS0} = V_{GS A} - 3 \quad (1)$$

$$V_{GS B} = 1.5 V_{GS A} \quad V_{DS B} = V_{D5A}$$



→ B je isto u TRIOBNOJ

$$V_{D5A} < 1$$

$$V_{DS B} < V_{GS}$$

PODRUČJE RA

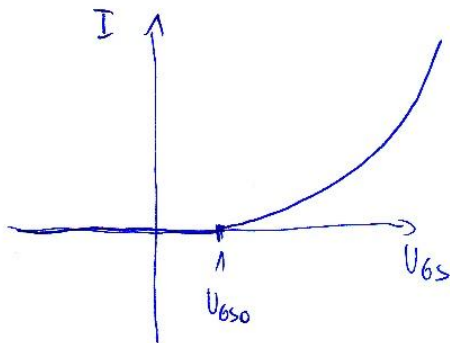
$$\begin{aligned} I_{DB} &= K \cdot \left[(V_{GB} - V_{GS0}) \cdot V_{DS B} - \frac{V_{DS B}^2}{2} \right] \\ &= K \cdot \left[(1.5 \cdot V_{GS A} - (V_{GS A} - 3)) V_{DS B} - \frac{V_{DS B}^2}{2} \right] \\ &\quad \downarrow \\ &\quad 2V \end{aligned}$$

$$\dots = 24 = 3 \cdot [(1.5 V_{GS A} + 3) \cdot 2 - 2]$$

$$\underline{V_{GS A} = 4 \text{ V}} \rightarrow \underline{V_{GS B} = 6 \text{ V}} \quad \underline{V_{GS0} = 1 \text{ V}}$$

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b) ODREDI TIP MOSFETA

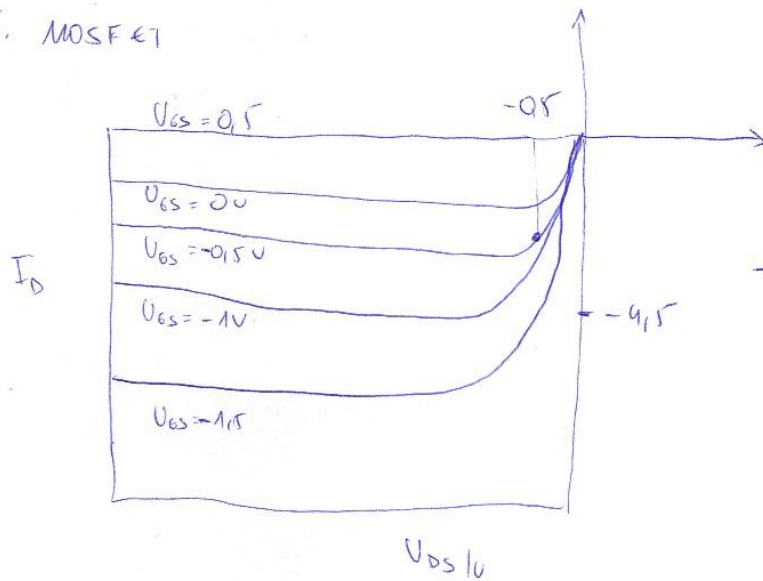
N MOSFET U_{GS} pozitivna struja n $U_{GS0} = 0 \quad I_D = 0 \rightarrow \text{OBOGAĆENI}$ c) ODREDI MAX STRUJA ODLODA MOSFETA UZ U_{GS4} iz tačke A

$$I_{D \max}(U_{GS4}) = I_{D \text{ zasić}}(U_{GS4})$$

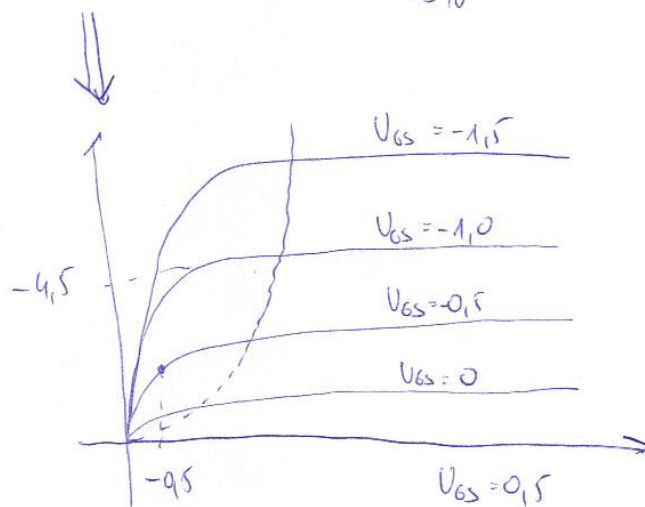
$$= \frac{K}{2} (U_{GS4} - U_{GS0})^2 = \dots = \underline{\underline{13,5 \text{ mA}}}$$

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5. MOSFET



→ 3 KUADRA
→ P KANA MOSFET

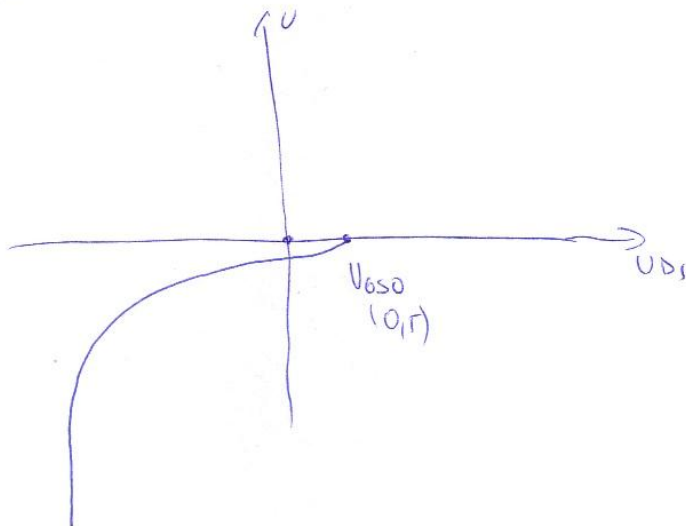


V_{GS} postaje NEGATIVNI STRUJ I_D POZNAJE P-MOS

$V_{GS0} = 0.5V$ $I = 0$ → napon praga

Ele 14

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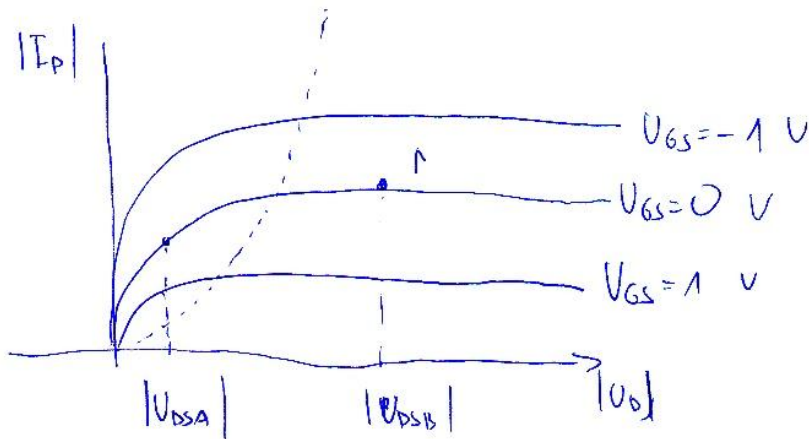
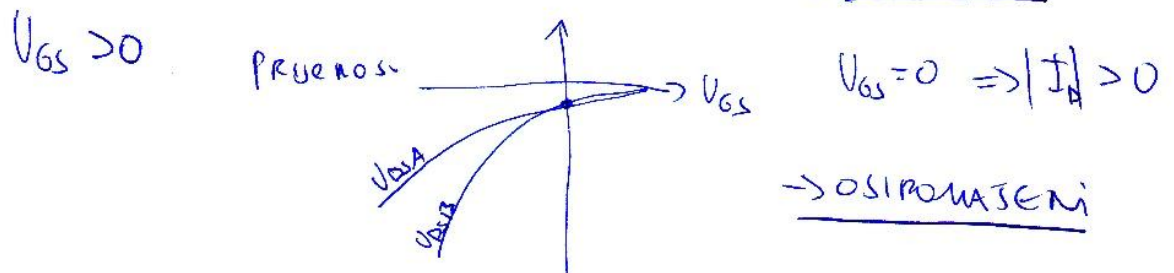
P-MOS

$$V_{GS} = 0V \rightarrow (I_D) > 0$$

Kanal P or \rightarrow 0 Siromačen

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Na slici 12A MOSFET

 g_{mA} i g_{mB} i koji tip→ kako V_{GS} negativu $|I_D|$ raste (po mode) P-mos

točka A → TRIODNO

$$g_m = \frac{\partial I_D}{\partial V_{GS}} = k \cdot V_{GS}$$

točka B → ZASIČEN

$$g_m = \frac{\partial I_D}{\partial V_{GS}} = k \cdot (V_{GS} - V_{GS0})$$

$$\boxed{U \text{ TRIODNO}} \quad |V_{DS}| < |V_{GS} - V_{GS0}|$$

$$k \cdot V_{GS} < k(V_{GS} - V_{GS0})$$

$$g_{mA} < g_{mB}$$